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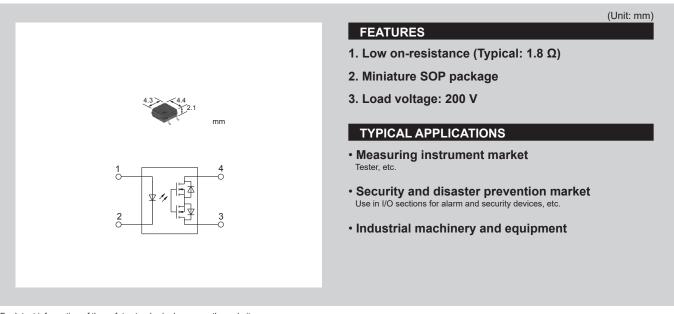
PhotoMOS®







Low on-resistance, Miniature (SOP 4-pin), 200 V load voltage



^{*}For latest information of the safety standard, please see the website.

TYPES

Packing quantity: Inner carton (Tube packing style) 100 pieces, Outer carton 2,000 pieces Inner carton (Tape and reel packing style) 1,000 pieces, Outer carton 1,000 pieces

	*Outpu	it rating	Part No.			
	Load voltage	Load current		Tape and reel packing X style (Picked from the 1/2-pin side)	Tape and reel packing Z style (Picked from the 3/4-pin side)	
AC/DC dual use	200 V	0.4 A	AQY217GS	AQY217GSX	AQY217GSZ	

Note: For space reasons, the three initial letters of the part number "AQY", the small outline package indicator "S" and the packing style indicator "X" or "Z" are not marked on the device.

*Indicate the peak AC and DC values.

RATING

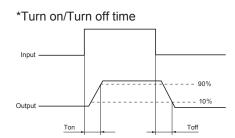
Absolute maximum ratings (Ambient temperature: 25°C)

	Item	Symbol	AQY217GS	Remarks
	LED forward current	lF	50 mA	
Input LED reverse voltage Peak forward current	VR	5 V		
	Peak forward current	IFP	1 A	f = 100 Hz, Duty factor = 0.1%
	Power dissipation		75 mW	
	Load voltage (peak AC)	VL	200 V	
	Continuous load current	lι	0.4 A	Peak AC, DC
Output	Output Peak load current	Ipeak	1.2 A	100 ms (1 shot), V _L = DC
	Power dissipation		400 mW	
	Total power dissipation	Рт	450 mW	
I/O isolation voltage		Viso	1,500 Vrms	
Operating ambient temperature		Topr	–40 to +85°C	(Non-icing at low temperatures)
Storage temperature		Tstg	–40 to +100°C	

Electrical characteristics (Ambient temperature: 25°C)

Item		Symbol	AQY217GS	Conditions		
LED opera	LED energies gurrent	Typical	I Fon	0.75 mA	l. = 100 m 1	
	LED operate current	Maximum	IFon	3.0 mA	I _L = 100 mA	
Input	LED turn off current	Minimum	I Foff	0.2 mA	I∟ = 100 mA	
прис		Typical	IFoff	0.7 mA	IL - TOO IIIA	
	LED dropout voltage	Typical	VF	1.32 V (1.14 V at I _F = 5 mA)	I _F = 50 mA	
	LED dropout voltage	Maximum		1.5 V	IF = 50 IIIA	
	On maniataman	Typical	J	1.8 Ω	I _F = 5 mA	
On resistance Output	On resistance	Maximum	Ron	2.5 Ω	I∟= Max. Within 1 s	
Off state leakage current		Maximum	Leak	1 μΑ	I₅ = 0 mA V∟ = Max.	
	··	Typical	Ton	1.2 ms	I⊧ = 5 mA I∟ = 100 mA	
	*Turn on time	Maximum	I on	5 ms	V _L = 10 V	
	*T (()	Typical	Toff	0.03 ms	I _F = 5 mA	
*Turn off time	Turn oil time	Maximum	I off	0.2 ms	I∟ = 100 mA V∟ = 10 V	
Transfer characteristics	I/O capacitance	Typical	Ciso	0.8 pF	f = 1 MHz	
onaractoricaco		Maximum	Ciso	1.5 pF	$V_B = 0 V$	
	I/O isolation resistance	Minimum	Riso	1,000 ΜΩ	500 V DC	
	Maximum switching frequency	Maximum	_	10 cps	I _F = 5 mA Duty = 50 % I _L = Max., V _L = Max.	

Note: For the connection method, please refer to the schematic and wiring diagrams.



■ Recommended operating conditions (Ambient temperature: 25°C)

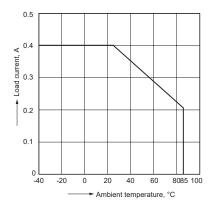
Please use under recommended operating conditions to obtain expected characteristics.

	Symbol	Minimum	Maximum	Unit	
LED fo	rward current	lF	5	30	mA
AQY217GS	Load voltage (peak AC)	VL	_	160	V
	Continuous load current	IL	_	0.4	Α

REFERENCE DATA

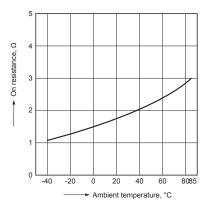
Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40 to +85°C



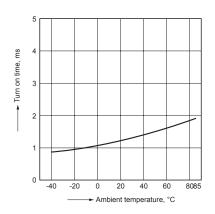
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4 LED forward current: 5 mA; Load voltage: Max. (DC) Continuous load current: Max.(DC)



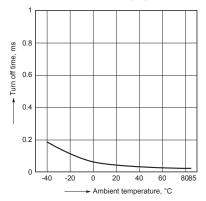
3. Turn on time vs. ambient temperature characteristics

LED forward current: 5 mA, Load voltage: 10 V (DC) Continuous load current: 100 mA (DC)

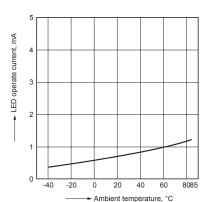


Turn off time vs. ambient temperature characteristics
 LED forward current: 5 mA

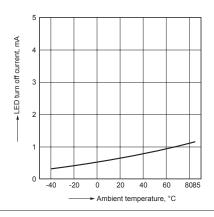
LED forward current: 5 mA Load voltage: 10 V (DC) Continuous load current: 100 mA (DC)



 LED operate current vs. ambient temperature characteristics
 Load voltage: 10 V (DC)
 Continuous load current: 100 mA (DC)

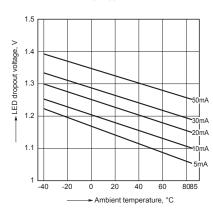


 LED turn off current vs. ambient temperature characteristics
 Load voltage: 10 V (DC)
 Continuous load current: 100 mA (DC)



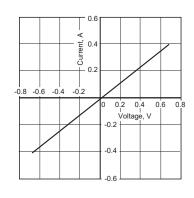
7. LED dropout voltage vs. ambient temperature characteristics

LED forward current: 5 to 50 mA



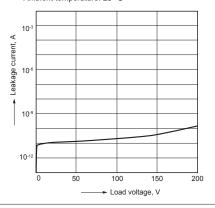
8. Current vs. voltage characteristics of output at MOS portion

Ambient temperature: 25 °C



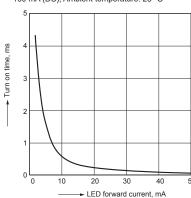
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4 Ambient temperature: 25 °C



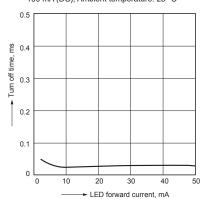
10. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4 Load voltage: 10 V (DC), Continuous load current: 100 mA (DC), Ambient temperature: 25 °C



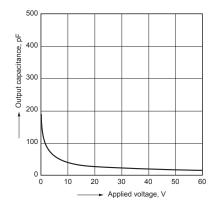
11. Turn off time vs. LED forward current

Measured portion: between terminals 3 and 4 Load voltage: 10 V (DC), Continuous load current: 100 mA (DC), Ambient temperature: 25 °C

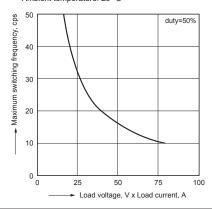


12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4 Frequency: 1 MHz, Ambient temperature: 25 $^{\circ}\text{C}$



 Maximum switching frequency vs. load voltage and load current LED forward current: 5 mA Ambient temperature: 25 °C



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